L Number	Hits	Scarch Text	DB	Time stamp	•
1	5	(semiconductor near (test or testing))	USPAT;	2002/05/28	
-	_	and ((digital adj tester) or (test adj	US-PGPUB;	16:55	
		(pattern or vector or stimuli))) and loop	EPO; JPO;		
		and (failure near2 rate)	DERWENT;		
I			IBM TDB		*
.4	7	("4055801" "4807161" "4866714"	USPĀT	2002/05/28	
		"4868785" "5001714" "5325309"		17:13	1
		"5371851").PN.	1		÷
15	9	· ·	USPAT	2002/05/28	,
				17:13	
- 1	90	((702/35,57-59,64,65,69,72,75-80,108,117-1	205PAT; 134, 1	8230-0128/60,51/6291).	ccls.)
ļ		and (semiconductor near2 (test or	US-PGPUB;	15:20	•
		testing))	EPO; JPO;	1	
		•	DERWENT;		
			IBM TDB		
.	45	((324/500,501,512,520-535,537,750-755,763,	785PA38,555,	62000,26/9015,762913,	702,703,
		and (semiconductor near2 (test or	US-PGPUB;	10:51	
}		testing)) and (heat or heating) and	EPO; JPO;		
1		(resistive or resistivity)	DERWENT;		.`
I		•	IBM_TDB		
.	38	((438/14-18).ccls.) and (semiconductor	USPAT;	2002/05/21	
1		near2 (test or testing)) and (heat or	US-PGPUB;	10:52	- -
		heating or temperature or thermal or	EPO; JPO;		1 .
1		thermally) and (resistive or resistivity)	DERWENT;		
İ			IBM_TDB		
-	30	((326/37-47,101).ccls.) and	USPĀT;	2002/05/21	
1		(semiconductor near2 (test or testing))	US-PGPUB;	10:52	
			EPO; JPO;		
			DERWENT;		
			IBM TDB		
-	18	((714/25,30,32,33,37,40,41,724-745).ccls.)	USPAT;	2002/05/21	
		and (semiconductor near2 (test or	US-PGPUB;	10:52	
		testing)) and (resistive or resistivity)	EPO; JPO;		
			DERWENT;		•
			IBM_TDB		
-	106	(semiconductor near (test or testing))	USPAT;	2002/05/22	
1		and (laser or (optical adj microscope))	US-PGPUB;	04:22	
1		and (resistive or resistivity)	EPO; JPO;		
			DERWENT;		
			IBM_TDB		
- [69	(semiconductor near2 (test or testing))	USPAT;	2002/05/21	
		and (state?change or state?changes or	US-PGPUB;	10:55	
		state?changing or (state adj (change or	EPO; JPO;		
1		changes or changing)))	DERWENT;		1.
			IBM_TDB		1
- [25	(semiconductor near2 (test or testing))	USPAT;	2002/05/21	
1		and (state?change or state?changes or	US-PGPUB;	10:55	
1		state?changing or (state adj (change or	EPO; JPO;		•
		changes or changing))) and (fail or fails	DERWENT;		· ·
1		or failed or failing or failure)	IBM_TDB		
-	7	(semiconductor near2 (test or testing))	USPAT;	2002/05/21	.
		and (state?change or state?changes or	US-PGPUB;	10:56	
		state?changing or (state adj (change or	EPO; JPO;		
		changes or changing))) and (fail or fails	DERWENT;		
		or failed or failing or failure) and	IBM_TDB		1.
ļ		(recover or recovers or recovered or			.
ŀ		recovering or recovery)			1
- [11	("3761695" "3783254" "3784907"	USPAT	2002/05/21	
		"3961251" "3961252" "4298980"		10:56	1
		"4329460" "4357703" "4504784"			.
1		"4519078" "4561095").PN.			
- ;	19	4669081.URPN.	USPAT	2002/05/22	
}				04:50	
- 🕴	0	4669081.URPN. and (laser or microscope	USPAT	2002/05/21	1
į		or resistive or resistivity)		10:58	i

				T 0000 105 155	
- !	6	<pre>(semiconductor near2 (test or testing)) and (burn?in or (burn adj in) or burnin)</pre>	USPAT; US-PGPUB;	2002/05/21	·
	!	and ((resistive or resistivity) near3	EPO; JPO;	10.38	
		(test or testing))	DERWENT;		
!_	11	(semiconductor near2 (test or testing))	IBM_TDB USPAT;	2002/05/21	1
		and (burn?in or (burn adj in) or burnin)	US-PGPUB;	10:59	
ĺ		and ((laser or optical) near2 (scan or	EPO; JPO;		1
<u> </u>		scanning))	DERWENT;		1
i _	119	edward near2 cole	IBM_TDB USPAT	2002/05/21	Ī
-	119	edward hearz core	USPAI	11:00	
-	1	"4698587".PN.	USPAT	2002/05/21	
				11:00	1
	14	5430305.URPN.	USPAT	2002/05/21	
_	4	 ("5422498" "5430305" "5708371"	USPAT	11:00	1
	4	"5844416").PN.	USFAI	11:00	}
-	4	6078183.URPN.	USPAT	2002/05/21	
				11:01	- 1
-	688	semiconductor and ((digital adj tester)	USPAT;	2002/05/22	ĺ
1		or (test adj pattern)) and loop	US-PGPUB; EPO; JPO;	06:25	
[DERWENT;		1
			IBM TDB		1
-	566	semiconductor and ((digital adj tester)	USPAT;	2002/05/22	
]		or (test adj pattern)) and loop and	US-PGPUB;	08:37	
		(error or fail or failure or fault)	EPO; JPO; DERWENT;		•
			IBM TDB		
-	8	semiconductor and ((digital adj tester))	USPAT;	2002/05/28	
		and loop and (error or fail or failure or	US-PGPUB;	11:50	
		fault)	EPO; JPO;		19
			DERWENT; IBM TDB		
-	0	semiconductor and ((digital adj tester))	USPAT;	2002/05/22	
		and (loop or cycle) and ((error or fail	US-PGPUB;	08:41	
		or failure or fault) near2 (inject or	EPO; JPO;		1
		injection))	DERWENT; IBM TDB		-
_	0	semiconductor and ((digital adj tester))	USPAT;	2002/05/22	
		and (rate) and ((error or fail or failure	US-PGPUB;	08:42	
		or fault) near2 (inject or injection))	EPO; JPO;		
_			DERWENT; IBM TDB		
	n	resistive near interconnection near	USPAT;	2002/05/28	
1	J	localization	US-PGPUB;	11:55	.]
			EPO; JPO;		
_			DERWENT;		
	18	 ("3840861" "3881172" "4520265"	IBM_TDB USPAT	2002/05/28	
	18	("3840861" "3881173" "4538265" "4633434" "4669081" "4670876"	USPAI	10:01	
		"4759019" "4779271" "4794517"		10.01	
		"4835459" "4999837" "5008885"			
		"5321698" "5495590" "5564014"			
1	12	"5671352" "5687338" "5701409").PN. semiconductor and ((digital adj tester))	USPAT;	2002/05/28	
	12	and (loop or (failure adj rate))	US-PGPUB;	11:54	
		, (EPO; JPO;		
			DERWENT;		.
	_	(comi conductor according to the conductor accor	IBM_TDB	2002 (05 (22	
	8	(semiconductor near (test or testing)) and (heat or heating) and laser and	USPAT; US-PGPUB;	2002/05/28	•
		((thin or thinning) near3 die)	EPO; JPO;	12.00	
			DERWENT;		
			IBM_TDB	1	
i		(semiconductor near (test and testing))	USPAT;	2002/05/28	1.0
-	2	\Schitconductor near \test and testing/			
-	2	and loop and (failure near rate)	US-PGPUB;	16:20	
_	2	and loop and (failure near rate)			

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